Low Forward Voltage Trench-based Schottky Rectifier

Features

- Fine Lithography Trench-based Schottky Technology for Very Low Forward Voltage and Low Leakage
- Fast Switching with Exceptional Temperature Stability
- Low Power Loss and Lower Operating Temperature
- Higher Efficiency for Achieving Regulatory Compliance
- Low Thermal Resistance
- High Surge Capability
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- Switching Power Supplies including Notebook / Netbook Adapters, ATX and Flat Panel Display
- High Frequency and DC-DC Converters
- Freewheeling and OR-ing diodes
- Reverse Battery Protection
- Instrumentation

Mechanical Characteristics

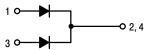
- Case: Epoxy, Molded
- Epoxy Meets Flammability Rating UL 94-0 @ 0.125 in
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Maximum for 10 sec



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PIN CONNECTIONS





MARKING DIAGRAM



TSV20H12G = Specific Device Code

A = Assembly Location

′ = Year

WW = Work Week

AKA = Polarity Designator

= Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit | |
|---|-------------------------|--|-------------|----|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | | V _{RRM} V _{RWM} V _R | 120 | V |
| Average Rectified Forward Current (Rated V_R , T_C = 124°C) (Rated V_R , T_C = 139°C) | Per device Per diode | I _{F(AV)} | 20 10 | А |
| Peak Repetitive Forward Current (Rated V_R , Square Wave, 20 kHz, T_C = 122°C) (Rated V_R , Square Wave, 20 kHz, T_C = 137°C) | Per device Per diode | I _{FRM} | 40 20 | А |
| Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz) | | I _{FSM} | 125 | А |
| Operating Junction Temperature | | TJ | -40 to +150 | °C |
| Storage Temperature | | T _{stg} | -40 to +150 | °C |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

| Rating | | | Value | Unit |
|----------------------------|---|--|-----------|--------------|
| Typical Thermal Resistance | Typical Thermal Resistance Junction-to-Case Junction-to-Ambient | | 1.7 50 | °C/W °C/W |

ELECTRICAL CHARACTERISTICS (Per Leg unless otherwise noted)

| Rating | Symbol | Тур | Max | Unit |
|---|----------------|-------|------|------|
| Maximum Instantaneous Forward Voltage (Note 1) | ٧ _F | | | V |
| $(I_F = 5 \text{ A}, T_J = 25^{\circ}\text{C})$ | | 0.679 | - | |
| (I _F = 10 A, T _J = 25°C) | | 0.931 | 1.03 | |
| $(I_F = 5 \text{ A}, T_J = 125^{\circ}\text{C})$ | | 0.562 | - | |
| $(I_F = 10 \text{ A}, T_J = 125^{\circ}\text{C})$ | | 0.653 | 0.71 | |
| Maximum Instantaneous Reverse Current (Note 1) | I _R | | | |
| $(V_R = 90 \text{ V}, T_J = 25^{\circ}\text{C})$ | | 2.3 | | μΑ |
| (V _R = 90 V, T _J = 125°C) | | 2.8 | | mA |
| (Rated dc Voltage, T _J = 25°C) | | 5.0 | 35 | μΑ |
| (Rated dc Voltage, T _J = 125°C) | | 4.6 | 20 | mA |

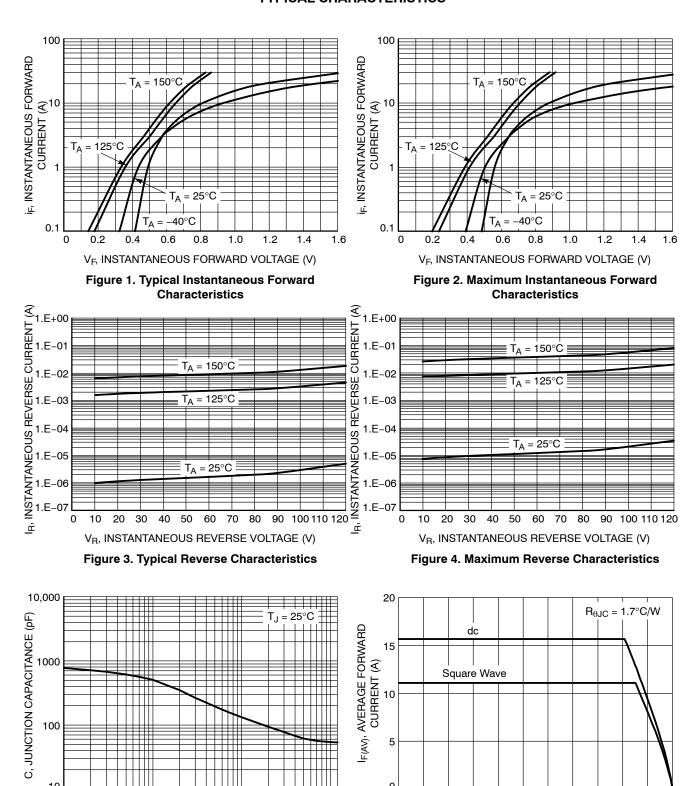
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

ORDERING INFORMATION

| Device | Package | Shipping |
|---------------|-----------------------|-----------------|
| NTSV20H120CTG | TO-220AB (Pb-Free) | 50 Units / Rail |

^{1.} Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤ 2.0%

TYPICAL CHARACTERISTICS



 $\label{eq:VR} V_R,\, \text{REVERSE VOLTAGE (V)}$ Figure 5. Typical Junction Capacitance

0.1

 T_C , CASE TEMPERATURE (°C) Figure 6. Current Derating per Leg

100 110 120 130 140 150

90

100

50

40

TYPICAL CHARACTERISTICS

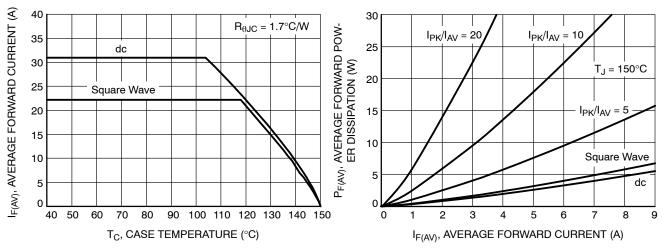


Figure 7. Current Derating, Device

Figure 8. Forward Power Dissipation

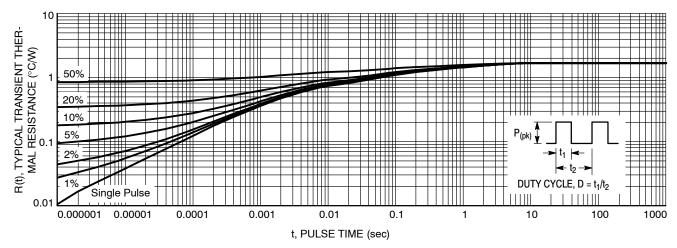
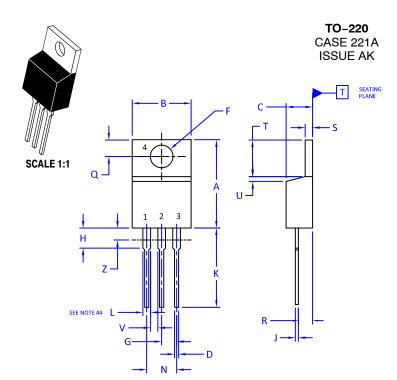


Figure 9. Typical Transient Thermal Response





DATE 13 JAN 2022

NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 2009.
- 2. CONTROLLING DIMENSION: INCHES
- 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

4. MAX WIDTH FOR F102 DEVICE = 1.35MM

| | INCHES | | MILLIMETERS | |
|-----|--------|-------|-------------|-------|
| DIM | MIN. | MAX. | MIN. | MAX. |
| Α | 0.570 | 0.620 | 14.48 | 15.75 |
| В | 0.380 | 0.415 | 9.66 | 10.53 |
| С | 0.160 | 0.190 | 4.07 | 4.83 |
| D | 0.025 | 0.038 | 0.64 | 0.96 |
| F | 0.142 | 0.161 | 3.60 | 4.09 |
| G | 0.095 | 0.105 | 2.42 | 2.66 |
| Н | 0.110 | 0.161 | 2.80 | 4.10 |
| J | 0.014 | 0.024 | 0.36 | 0.61 |
| К | 0.500 | 0.562 | 12.70 | 14.27 |
| L | 0.045 | 0.060 | 1.15 | 1.52 |
| N | 0.190 | 0.210 | 4.83 | 5.33 |
| Q | 0.100 | 0.120 | 2.54 | 3.04 |
| R | 0.080 | 0.110 | 2.04 | 2.79 |
| S | 0.045 | 0.055 | 1.15 | 1.41 |
| Т | 0.235 | 0.255 | 5.97 | 6.47 |
| U | 0.000 | 0.050 | 0.00 | 1.27 |
| V | 0.045 | | 1.15 | |
| Z | | 0.080 | | 2.04 |

| STYLE 1: PIN 1. 2. 3. 4. | COLLECTOR EMITTER | STYLE 2: PIN 1. 2. 3. 4. | COLLECTOR | STYLE 3: PIN 1. 2. 3. 4. | ANODE | 2. 3. | MAIN TERMINAL 1 MAIN TERMINAL 2 GATE MAIN TERMINAL 2 |
|--------------------------------------|----------------------|--------------------------------------|-------------------------|---------------------------------------|-------|---------------------------------------|---|
| STYLE 5: PIN 1. 2. 3. 4. | DRAIN SOURCE | STYLE 6: PIN 1. 2. 3. 4. | CATHODE ANODE | STYLE 7: PIN 1. 2. 3. 4. | ANODE | 2. 3. | CATHODE ANODE EXTERNAL TRIP/DELAY ANODE |
| STYLE 9: PIN 1. 2. 3. 4. | | | GATE SOURCE DRAIN | STYLE 11: PIN 1. 2. 3. 4. | | STYLE 12: PIN 1. 2. 3. 4. | MAIN TERMINAL 1 MAIN TERMINAL 2 GATE NOT CONNECTED |

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